



Low IBIAS, +1.4V/800nA, Rail-to-Rail Op Amps with +1.2V Buffered Reference

General Description

The single MAX4036/MAX4037 and dual MAX4038/MAX4039 operational amplifiers operate from a single +1.4V to +3.6V (without reference) or +1.8V to +3.6V (with reference) supply and consume only 800nA of supply current per amplifier, and 1.1 μ A for the optional reference. The MAX4036/MAX4038 feature a common-mode input voltage range from 0V to V_{DD} - 0.4V at V_{DD} = 1.4V. The MAX4037/MAX4039 feature a 1.232V voltage reference capable of sourcing 100 μ A and sinking 20 μ A.

The MAX4036–MAX4039s' rail-to-rail outputs drive 5k Ω loads to within 25mV of the rails. Ultra-low supply current, low operating voltage, and rail-to-rail outputs make the MAX4036–MAX4039 ideal for use in single-cell lithium-ion (Li+), or two-cell NiCd/NiMH/alkaline battery-powered applications.

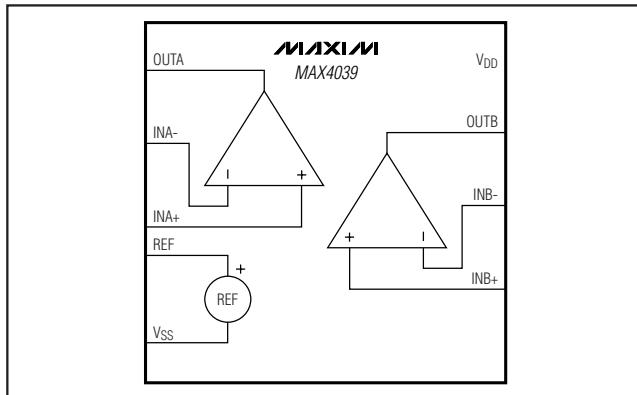
The MAX4036 is available in an SC70 package, the MAX4037 in a SOT23 package, and the MAX4038/MAX4039 in UCSP™, μ MAX®, and TDFN packages. All devices are specified over the -40°C to +85°C extended temperature range.

Applications

- Battery-Powered/Solar-Powered Systems
- Portable Medical Instrumentation
- Pagers and Cell Phones
- Micropower Thermostats and Potentiostats
- Electrometer Amplifiers
- Remote Sensor Amplifiers
- Active Badges
- pH Meters

μ MAX is a registered trademark and UCSP is a trademark of Maxim Integrated Products, Inc.

Functional Diagram



Features

- ♦ Ultra-Low 800nA per Amplifier Supply Current
- ♦ Ultra-Low 1.4V Supply Voltage Operation (1.8V for MAX4037/MAX4039)
- ♦ Rail-to-Rail Outputs Drive 5k Ω and 5000pF Load
- ♦ 1.232V \pm 0.5%, 120ppm/ $^{\circ}$ C (max) Reference (MAX4037/MAX4039)
- ♦ No External Reference Bypass Capacitor Required
- ♦ No Phase Reversal for Overdriven Inputs
- ♦ Low 1.0pA (typ) Input Bias Current
- ♦ Low 200 μ V Input Offset Voltage
- ♦ Unity-Gain Stable
- ♦ Available in Tiny UCSP, SC70, SOT23, TDFN, and μ MAX Packages

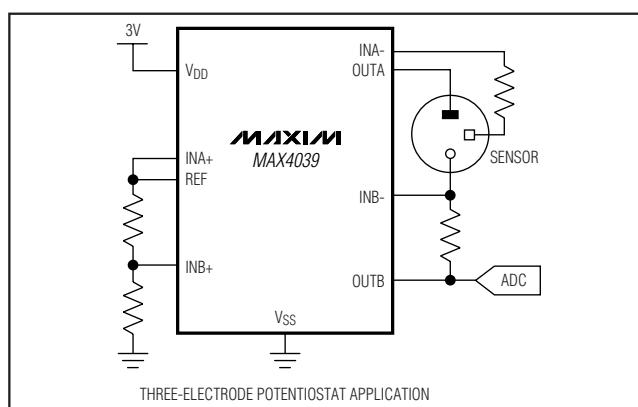
Ordering Information

PART	TEMP RANGE	PIN-PACKAGE	TOP MARK
MAX4036EXK-T	-40°C to +85°C	5 SC70-5	AFR
MAX4037EUT-T	-40°C to +85°C	6 SOT23-6	ABRX
MAX4038ETA	-40°C to +85°C	8 TDFN-EP*	AGO
MAX4038EUA	-40°C to +85°C	8 μ MAX	—
MAX4038EBL-T	-40°C to +85°C	9 UCSP-9	AEG
MAX4039EBL-T	-40°C to +85°C	9 UCSP-9	AEH
MAX4039ETB	-40°C to +85°C	10 TDFN-EP*	AAN
MAX4039EUB	-40°C to +85°C	10 μ MAX	—

*EP = Exposed paddle.

Pin Configurations and Selector Guide appear at end of data sheet.

Typical Operating Circuit



MAX4036-MAX4039

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ABSOLUTE MAXIMUM RATINGS

V _{DD} to V _{SS}	-0.3V to +4.0V
INA+, INB+, INA-, INB-, IN+, IN-, OUTA, OUTB, OUT, REF	(V _{SS} - 0.3V) to (V _{DD} + 0.3V)
OUTA, OUTB, OUT, REF Shorted to V _{SS} or V _{DD}	Continuous Maximum Continuous Power Dissipation (T _A = +70°C)
5-Pin SC70 (derate 3.1mW/°C above +70°C)	247mW
6-Pin SOT23 (derate 8.7mW/°C above +70°C)	696mW
8-Pin μMAX (derate 4.5mW/°C above +70°C)	362mW

8-Pin TDFN (derate 24.4mW/°C above +70°C)	1951mW
9-Bump UCSP (derate 5.2mW/°C above +70°C)	412mW
10-Pin μMAX (derate 5.6mW/°C above +70°C)	444mW
10-Pin TDFN (derate 24.4mW/°C above +70°C)	1951mW
Operating Temperature Range	-40°C to +85°C
Junction Temperature	+150°C
Storage Temperature Range	-65°C to +150°C
Lead Temperature (soldering, 10s)	+300°C

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

ELECTRICAL CHARACTERISTICS

(V_{DD} = +3V, V_{SS} = V_{CM} = 0V, V_{OUT}_ = V_{DD}/2, R_L to V_{DD}/2, C_L = 15pF, T_A = +25°C, unless otherwise specified.)

PARAMETER	SYMBOL	CONDITIONS		MIN	TYP	MAX	UNITS
Supply Voltage Range	V _{DD}	MAX4036/MAX4038, guaranteed by PSRR tests		1.4		3.6	V
		MAX4037/MAX4039, guaranteed by PSRR and line regulation tests		1.8		3.6	
Supply Current	I _{DD}	MAX4036	V _{DD} = 1.4V		0.8	1.2	μA
			V _{DD} = 3.6V		0.9	1.3	
		MAX4037	V _{DD} = 1.8V		1.9	2.4	
			V _{DD} = 3.6V		2.0	2.5	
		MAX4038	V _{DD} = 1.4V		1.7	2.3	
			V _{DD} = 3.6V		1.9	2.5	
		MAX4039	V _{DD} = 1.8V		2.8	4.0	
			V _{DD} = 3.6V		3.0	4.1	

OPERATIONAL AMPLIFIERS

Input Offset Voltage	V _{OS}			±0.2	±2.0	mV
Input Bias Current	I _B	(Note 1)		±1.0	±10	pA
Input Offset Current	I _{OS}	(Note 1)		±0.3	±20	pA
Input Common-Mode Voltage Range	V _{CM}	Guaranteed by CMRR test	V _{DD} = 1.4V (MAX4036/MAX4038 only)	V _{SS}	V _{DD} - 0.4	V
			V _{DD} = 1.8V	V _{SS}	V _{DD} - 0.3	
			V _{DD} = 3.3V	V _{SS}	V _{DD} - 0.2	
Common-Mode Rejection Ratio	CMRR	V _{DD} = 1.4V, V _{SS} ≤ V _{CM} ≤ (V _{DD} - 0.4V) (MAX4036/MAX4038 only)		50	70	dB
		V _{DD} = 1.8V, V _{SS} ≤ V _{CM} ≤ (V _{DD} - 0.3V)		50	70	
		V _{DD} = 3.3V, V _{SS} ≤ V _{CM} ≤ (V _{DD} - 0.2V)		56	76	
Power-Supply Rejection Ratio	PSRR	1.4V ≤ V _{DD} ≤ 3.6V (MAX4036/MAX4038 only)		62	82	dB
		1.8V ≤ V _{DD} ≤ 3.6V		62	84	

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ELECTRICAL CHARACTERISTICS (continued)

($V_{DD} = +3V$, $V_{SS} = V_{CM} = 0V$, $V_{OUT_} = V_{DD}/2$, R_L to $V_{DD}/2$, $C_L = 15pF$, $T_A = +25^\circ C$, unless otherwise specified.)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
Large-Signal Voltage Gain	AVOL	$R_L = 100k\Omega$, $50mV \leq V_{OUT} \leq (V_{DD} - 50mV)$	80	108		dB
		$R_L = 5k\Omega$, $150mV \leq V_{OUT} \leq (V_{DD} - 150mV)$	78	105		
Output Voltage Swing High	V _{DD} - V _{OH}	$R_L = 100k\Omega$		2	5	mV
		$R_L = 5k\Omega$		25	50	
Output Voltage Swing Low	V _{OL} - V _{SS}	$R_L = 100k\Omega$		2	5	mV
		$R_L = 5k\Omega$		25	50	
Output Short-Circuit Current	I _{SCO}	To V_{DD} or V_{SS}		±13		mA
Gain-Bandwidth Product	GBW			4		kHz
Phase Margin	θ_M			90		Degrees
Slew Rate	SR			0.4		V/ms
Power-On Time	t _{ON}	(Note 3)		0.25		ms
Input Noise-Voltage Density	e _n	f = 1kHz		500		nV/ $\sqrt{\text{Hz}}$
Capacitive-Load Stability	C _{LOAD}	A _{VCL} = 1V/V, no sustained oscillations		5000		pF
REFERENCE (MAX4037/MAX4039)						
Reference Voltage	V _{REF}		1.226	1.232	1.238	V
Line Regulation	$\Delta V_{REF}/\Delta V_{DD}$	$V_{DD} = +1.8V$ to $+3.6V$		0.3		%/V
Load Regulation	$\Delta V_{REF}/\Delta I_{LOAD}$	$0 \leq I_{LOAD} \leq 100\mu A$, sourcing		0.0015		%/ μA
		$-20\mu A \leq I_{LOAD} \leq 0$, sinking		0.0075		
Reference Output Voltage Noise	e _n	0.1Hz to 10Hz		60		$\mu\text{V}_{\text{P-P}}$
Output Short-Circuit Current	I _{SCR}	Short to V_{DD}		0.25		mA
		Short to V_{SS}		1.9		
Capacitive-Load Stability Range	C _{LOAD}	(Note 1)	0	250		pF

ELECTRICAL CHARACTERISTICS

($V_{DD} = +3V$, $V_{SS} = V_{CM} = 0V$, $V_{OUT_} = V_{DD}/2$, R_L to $V_{DD}/2$, $C_L = 15pF$, $T_A = T_{MIN}$ to T_{MAX} , unless otherwise specified.) (Note 2)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
Supply Voltage Range	V _{DD}	MAX4036/MAX4038, guaranteed by PSRR test	1.4		3.6	V
		MAX4037/MAX4039, guaranteed by PSRR and line regulation tests	1.8		3.6	
Supply Current	I _{DD}	MAX4036	$V_{DD} = 1.4V$		1.7	μA
			$V_{DD} = 3.6V$		1.8	
		MAX4037	$V_{DD} = 1.8V$		3.1	
			$V_{DD} = 3.6V$		3.2	
		MAX4038	$V_{DD} = 1.4V$		2.9	
			$V_{DD} = 3.6V$		3.2	
		MAX4039	$V_{DD} = 1.8V$		5.2	
			$V_{DD} = 3.6V$		5.3	

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ELECTRICAL CHARACTERISTICS (continued)

($V_{DD} = +3V$, $V_{SS} = V_{CM} = 0V$, $V_{OUT_} = V_{DD}/2$, R_L to $V_{DD}/2$, $C_L = 15pF$, $T_A = T_{MIN}$ to T_{MAX} , unless otherwise specified.) (Note 2)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
OPERATIONAL AMPLIFIERS						
Input Offset Voltage	V_{OS}			± 8		mV
Input Offset Voltage Temperature Coefficient	TCV_{OS}			± 1		$\mu V/{\circ}C$
Input Bias Current	I_B			± 100		pA
Input Offset Current	I_{OS}			± 200		pA
Input Common-Mode Voltage Range	V_{CM}	Guaranteed by CMRR test	$V_{DD} = 1.4V$ (MAX4036/MAX4038 only)	V_{SS}	$V_{DD} - 0.4$	V
			$V_{DD} = 1.8V$	V_{SS}	$V_{DD} - 0.4$	
			$V_{DD} = 3.3V$	V_{SS}	$V_{DD} - 0.2$	
Common-Mode Rejection Ratio	CMRR	$V_{DD} = 1.4V$, $V_{SS} \leq V_{CM} \leq (V_{DD} - 0.4V)$ (MAX4036/MAX4038 only)	44			dB
		$V_{DD} = 1.8V$, $V_{SS} \leq V_{CM} \leq (V_{DD} - 0.4V)$	50			
		$V_{DD} = 3.3V$, $V_{SS} \leq V_{CM} \leq (V_{DD} - 0.2V)$	52			
Power-Supply Rejection Ratio	PSRR	$1.4V \leq V_{DD} \leq 3.6V$ (MAX4036/MAX4038 only)	60			dB
		$1.8V \leq V_{DD} \leq 3.6V$	60			
Large-Signal Voltage Gain	A_{VOL}	$R_L = 100k\Omega$, $50mV \leq V_{OUT} \leq (V_{DD} - 50mV)$	75			dB
		$R_L = 5k\Omega$, $150mV \leq V_{OUT} \leq (V_{DD} - 150mV)$	73			
Output Voltage Swing High	$V_{DD} - V_{OH}$	$R_L = 100k\Omega$		10		mV
		$R_L = 5k\Omega$		100		
Output Voltage Swing Low	$V_{OL} - V_{SS}$	$R_L = 100k\Omega$		10		mV
		$R_L = 5k\Omega$		100		
REFERENCE (MAX4037/MAX4039)						
Reference Voltage Temperature Coefficient	TCVREF	(Note 1)	$MAX4037EUT-T$, $MAX4039ETB$, $MAX4039EUB$	25	120	ppm/ $^{\circ}C$
			$MAX4039EBL-T$	35	200	
Line Regulation	$\Delta V_{REF}/\Delta V_{DD}$	$V_{DD} = 1.8V$ to $3.6V$			0.6	%/V
Load Regulation	$\Delta V_{REF}/\Delta I_{LOAD}$	$0 \leq I_{LOAD} \leq 100\mu A$, sourcing			0.003	%/ μA
		$-20\mu A \leq I_{LOAD} \leq 0$, sinking			0.015	
Capacitive-Load Stability Range	C_{LOAD}	(Note 1)		0	250	pF

Note 1: Guaranteed by design.

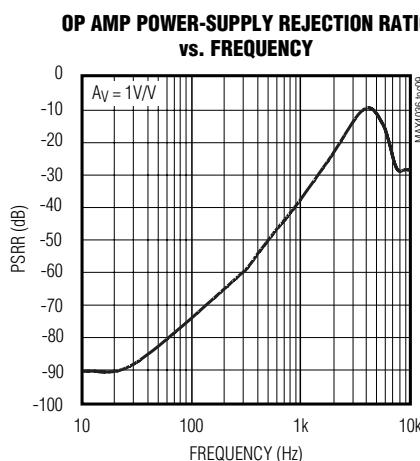
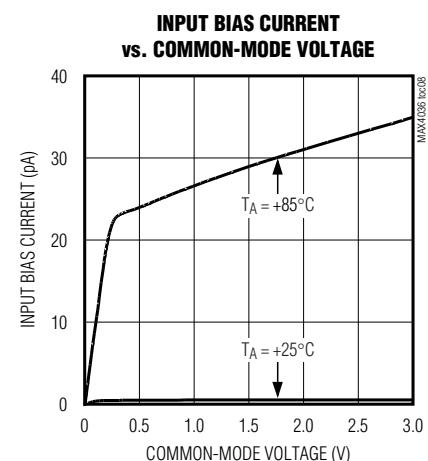
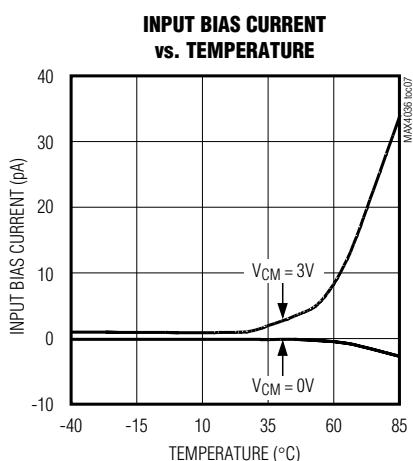
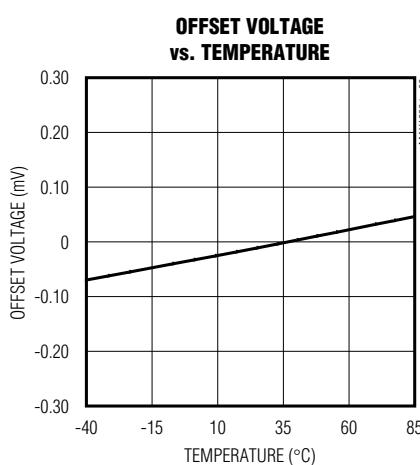
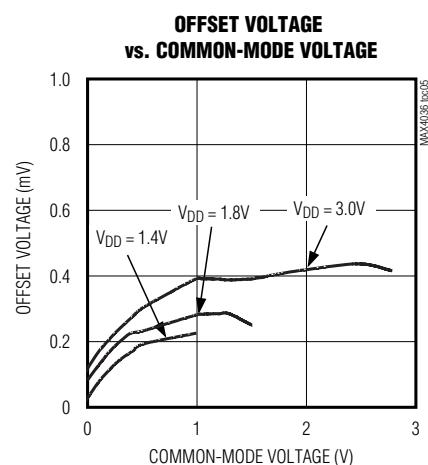
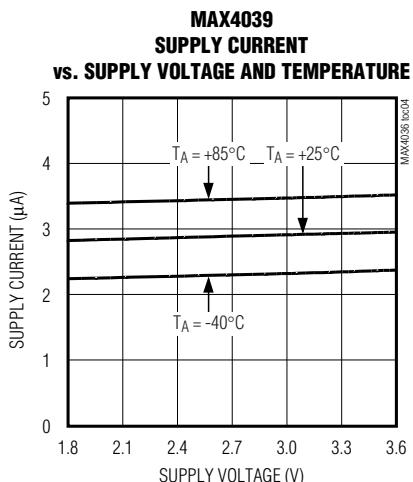
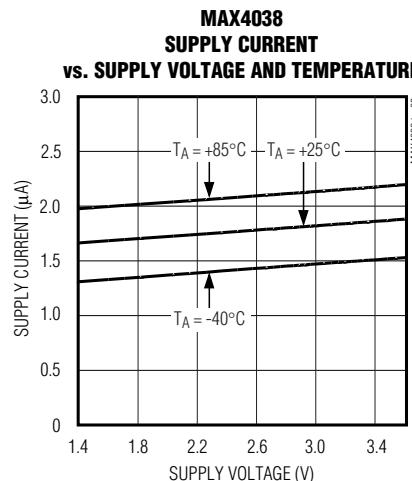
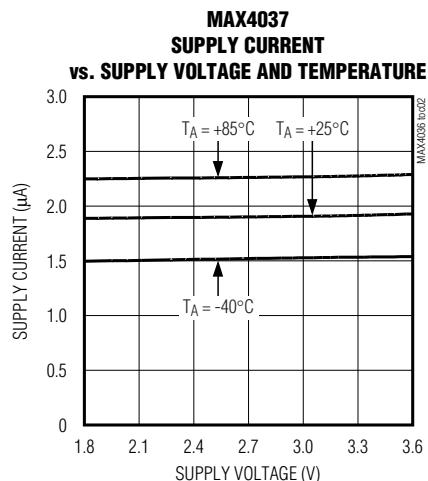
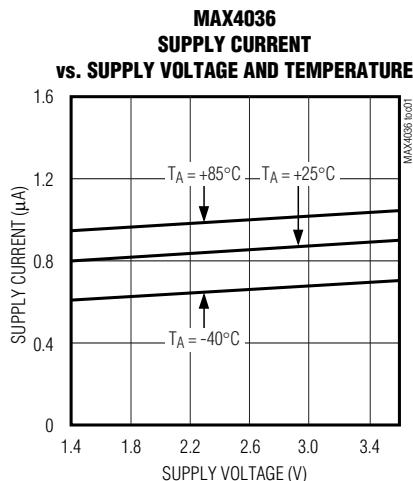
Note 2: All devices are production tested at $T_A = +25^{\circ}C$. All temperature limits are guaranteed by design.

Note 3: Output settles within 1% of final value.

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Typical Operating Characteristics

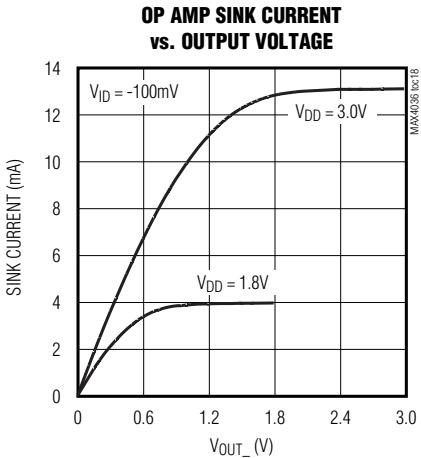
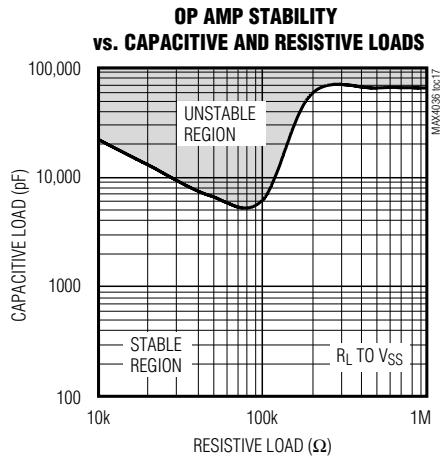
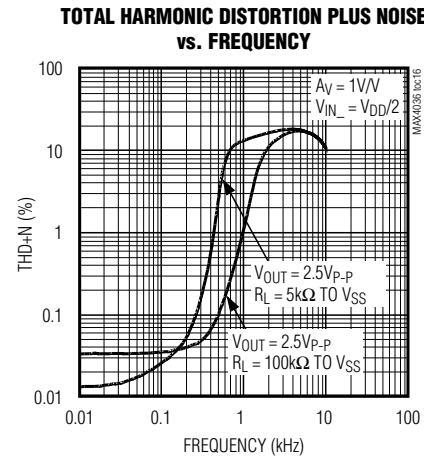
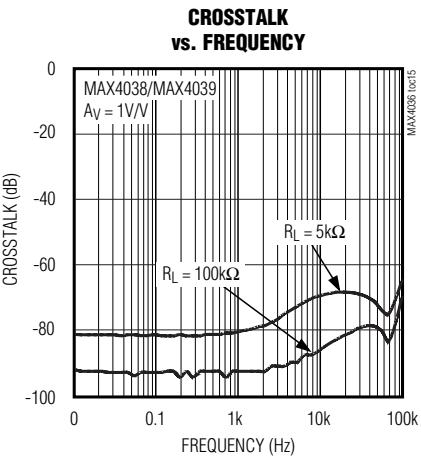
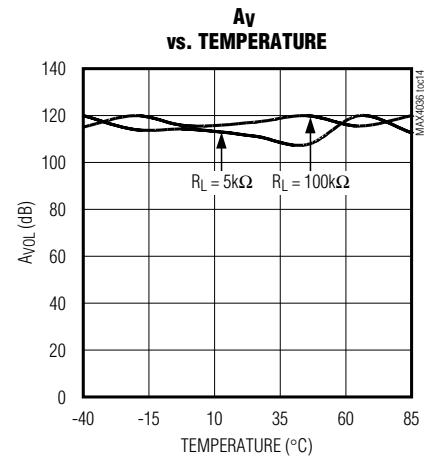
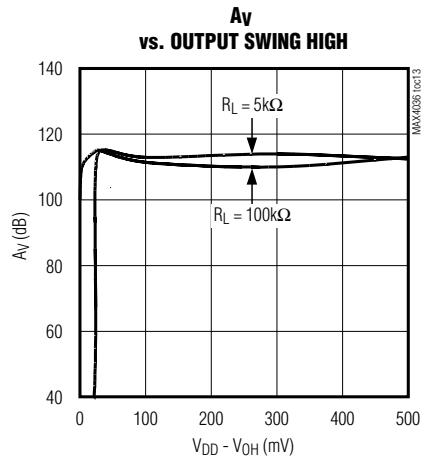
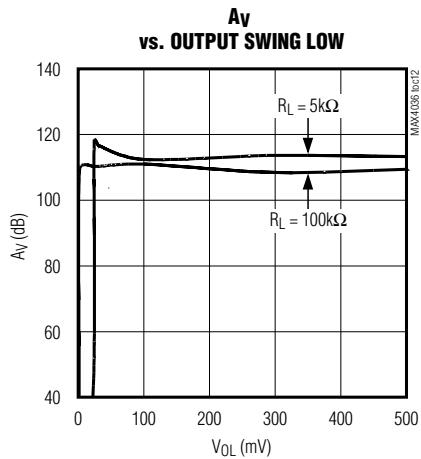
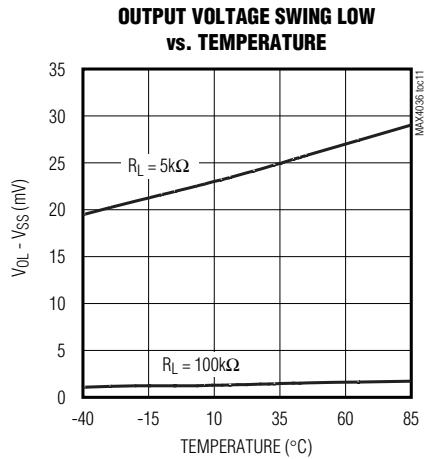
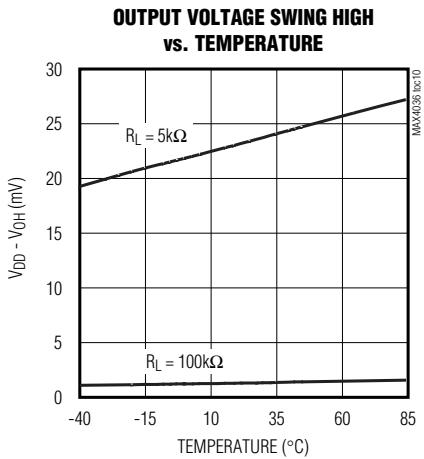
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Typical Operating Characteristics (continued)

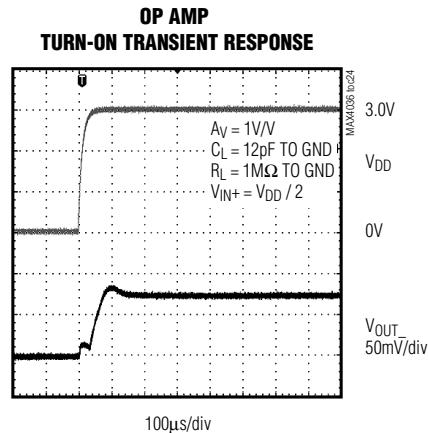
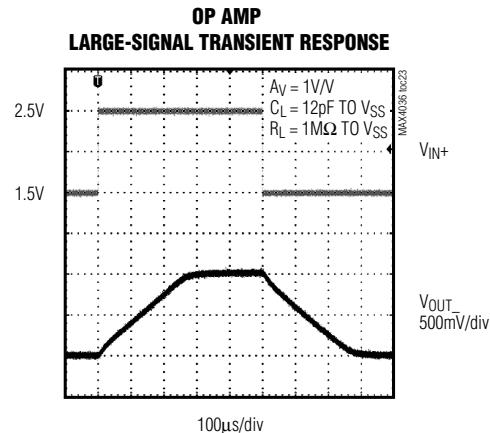
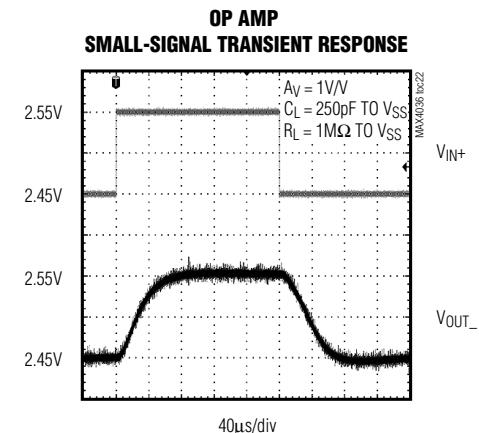
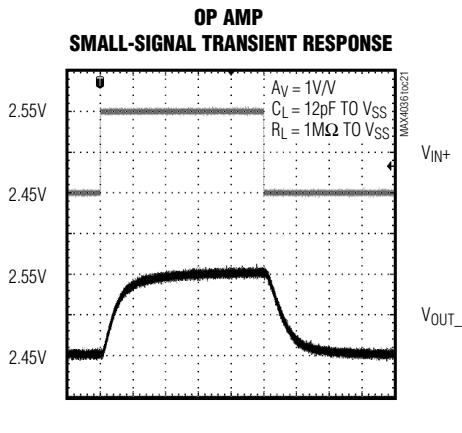
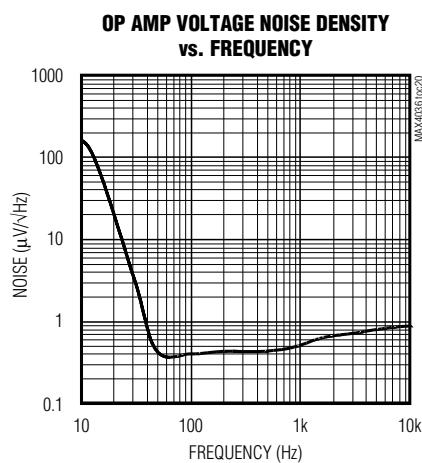
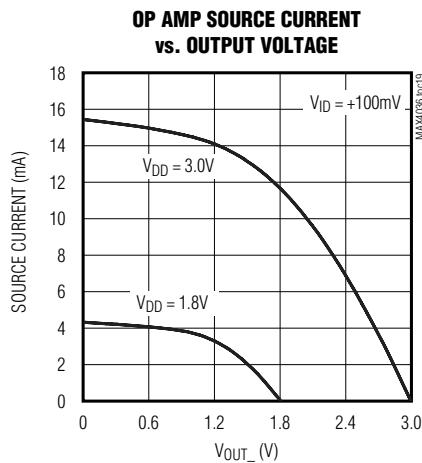
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Typical Operating Characteristics (continued)

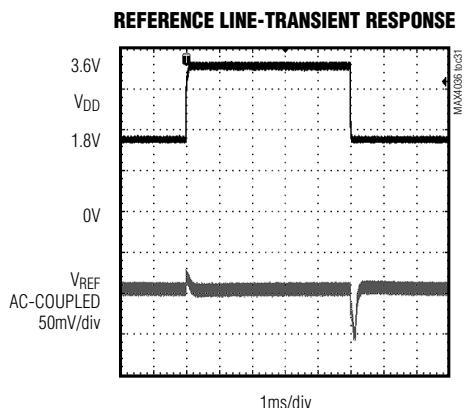
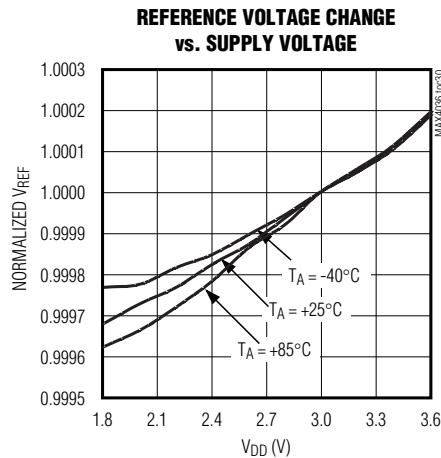
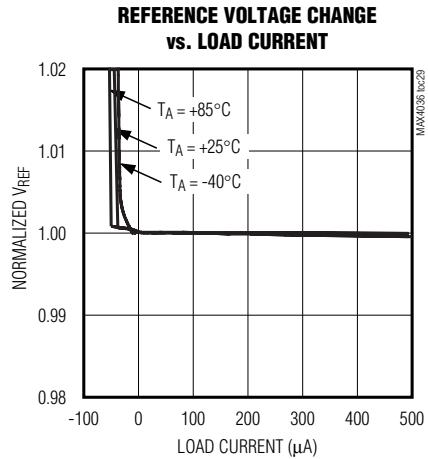
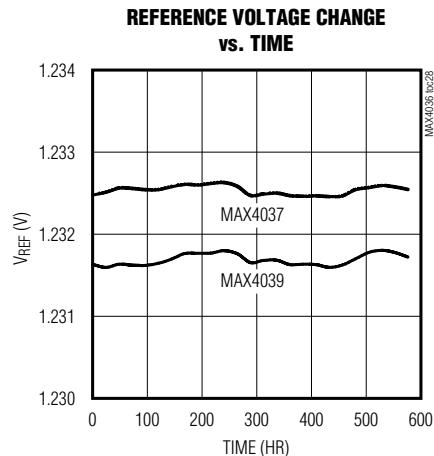
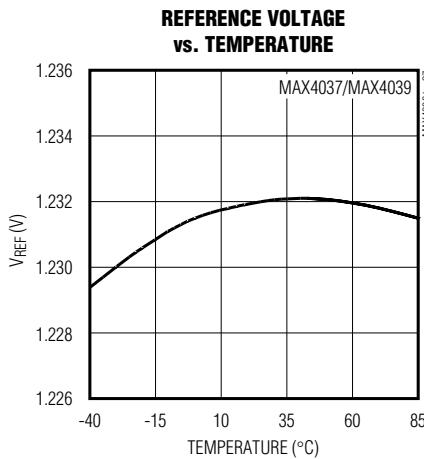
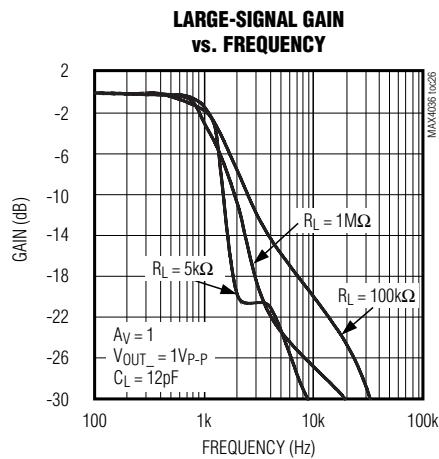
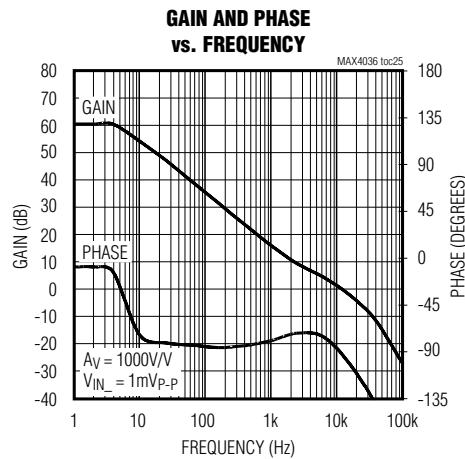
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Typical Operating Characteristics (continued)

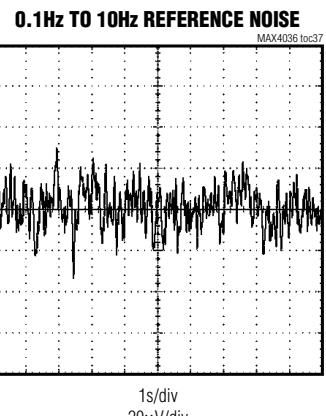
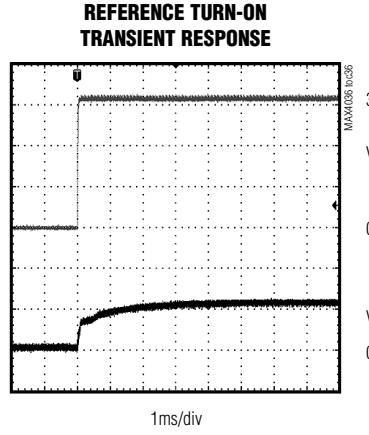
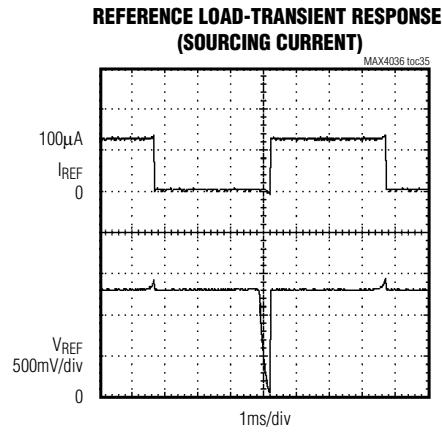
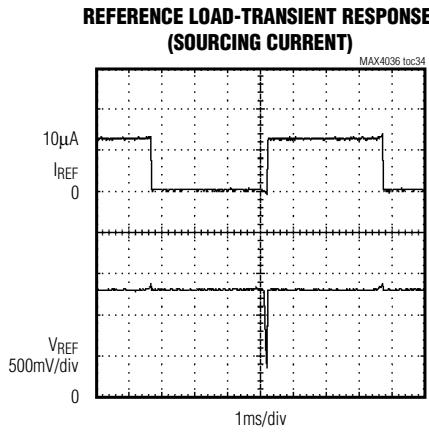
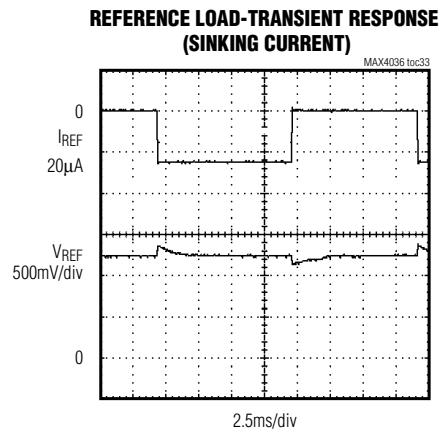
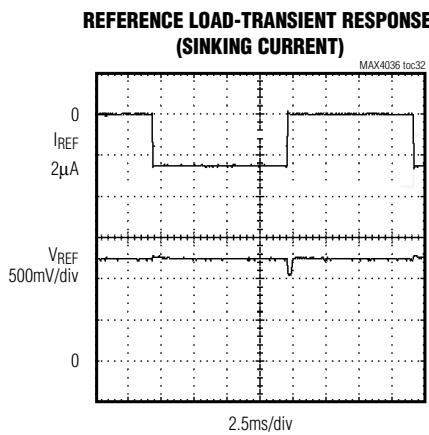
($V_{DD} = 3V$, $V_{SS} = V_{CM} = 0V$, R_L to $V_{DD}/2$, $T_A = +25^{\circ}\text{C}$, unless otherwise noted.)



Low I_{Bias}, +1.4V/800nA, Rail-to-Rail Op Amps with +1.2V Buffered Reference

Typical Operating Characteristics (continued)

(V_{DD} = 3V, V_{SS} = V_{CM} = 0V, R_L to V_{DD}/2, T_A = +25°C, unless otherwise noted.)



Low IBIAS, +1.4V/800nA, Rail-to-Rail Op Amps with +1.2V Buffered Reference

Pin Description

PIN						NAME	FUNCTION		
MAX4036	MAX4037	MAX4038		MAX4039					
		μ MAX/TDFN	UCSP	μ MAX/TDFN	UCSP				
1	3	—	—	—	—	IN+	Noninverting Amplifier Input		
2	2	4	A2	5	A2	Vss	Negative Power-Supply Voltage		
3	4	—	—	—	—	IN-	Inverting Amplifier Input		
4	1	—	—	—	—	OUT	Amplifier Output		
5	6	8	C2	10	C2	VDD	Positive Power-Supply Voltage		
—	5	—	—	6	B2	REF	Reference Voltage Output		
—	—	1	C1	1	C1	OUTA	Amplifier Output (Channel A)		
—	—	2	B1	2	B1	INA-	Inverting Amplifier Input (Channel A)		
—	—	3	A1	3	A1	INA+	Noninverting Amplifier Input (Channel A)		
—	—	5	A3	7	A3	INB+	Noninverting Amplifier Input (Channel B)		
—	—	6	B3	8	B3	INB-	Inverting Amplifier Input (Channel B)		
—	—	7	C3	9	C3	OUTB	Amplifier Output (Channel B)		
—	—	—	B2	4	—	N.C.	No Connection. Not internally connected.		
—	—	—	—	—	—	EP (TDFN only)	Exposed Paddle. Solder EP to Vss or leave unconnected (TDFN packages only).		

Detailed Description

The MAX4036–MAX4039 consume an ultra-low supply current and have rail-to-rail output stages specifically designed for low-voltage operation. The input common-mode voltage range extends from $V_{DD} - 0.4V$ to V_{SS} , although full rail-to-rail input range is possible with degraded performance when operating from a supply voltage above 3.0V. The input offset voltage is typically 200 μ V. Low-operating supply voltage, low supply current, and rail-to-rail outputs make the MAX4036–MAX4039 an excellent choice for precision or general-purpose low-voltage, battery-powered systems.

Rail-to-Rail Outputs

The MAX4036–MAX4039 output stages can drive a 5k Ω load and still swing to within 40mV of the rails. Figure 1 shows the output voltage swing of the MAX4036–MAX4039 configured as a unity-gain buffer, powered from a single 2.4V supply. The output for this setup typically swings from 5mV to $V_{DD} - 5mV$ with a 100k Ω load.

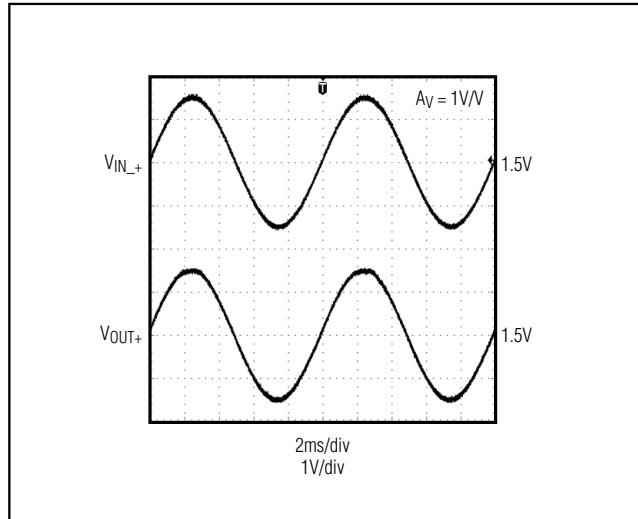


Figure 1. Rail-to-Rail Input/Output Voltage Range

Low IBIAS, +1.4V/800nA, Rail-to-Rail Op Amps with +1.2V Buffered Reference

Applications Information

Power-Supply Considerations

The MAX4036–MAX4039 operate from a single 1.4V (MAX4036/MAX4038) or 1.8V (MAX4037/MAX4039) to 3.6V supply. A high amplifier power-supply rejection ratio of 82dB and the excellent reference line regulation allow the devices to be powered directly from a decaying battery voltage, simplifying design and extending battery life. The MAX4036–MAX4039 are ideally suited for low-voltage battery-powered systems. The *Typical Operating Characteristics* show the changes in supply current and reference output as a function of supply voltage.

Power-Up Settling Time

The MAX4036–MAX4039 typically require 0.25ms to power-up. During this startup time, the output is indeterminate. The application circuit should allow for this initial delay. See the *Typical Operating Characteristics* for amplifier and reference settling time curves.

Driving Capacitive Loads: Op Amps

The MAX4036–MAX4039 amplifier(s) require no output capacitor for stability, and are unity-gain stable for loads up to 5000pF. Applications that require greater capacitive-drive capability should use an isolation resistor between the output and the capacitive load (Figure 2). Note that this solution reduces the gain and output voltage swing because R_{ISO} forms a voltage-divider with the load resistor.

Crossover Distortion

The MAX4036–MAX4039 output stages are capable of sourcing and sinking currents with orders of magnitude greater than the stages' quiescent current, which is less than 1 μ A. This ability to drive heavy loads with such a small quiescent current introduces crossover

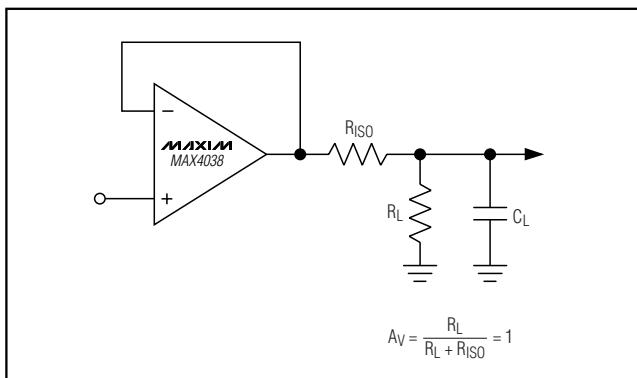


Figure 2. Using a Resistor to Isolate a Capacitive Load from the Op Amp

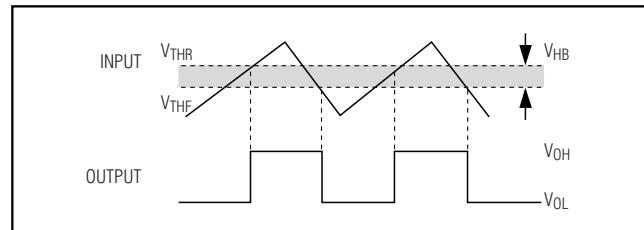


Figure 3. Hysteresis

distortion as the output stage passes between sinking and sourcing. In the crossover regions, the output impedance of the MAX4036–MAX4039 increases substantially, thereby changing the load-driving characteristics. The distortion can be greatly reduced by increasing the load resistance. For applications where low load resistance is required, bias the load such that the output current is always in one direction, to avoid crossover distortion.

Reference Bypassing

The MAX4037/MAX4039 reference requires no external capacitors.

Using the MAX4036–MAX4039 as a Comparator

Although optimized for use as an operational amplifier, the MAX4036–MAX4039 can be used as a rail-to-rail I/O comparator (Figures 3, 4). External hysteresis can be used to minimize the risk of output oscillation. The positive feedback circuit, shown in Figure 4, causes the input threshold to change when the output voltage changes state.

Battery Monitoring Using the MAX4037/MAX4039 and Hysteresis

The internal reference and low operating voltage of the MAX4037/MAX4039 make the devices ideal for battery-monitoring applications. Hysteresis can be set using resistors as shown in Figure 4, and the following design procedure:

- 1) Choose R_3 . The input bias current of IN_+ is under 100pA over temperature, so a current through R_3 around 100nA maintains accuracy. The current through R_3 at the trip point is V_{REF} / R_3 , or 100nA for $R_3 = 12M\Omega$. $10M\Omega$ is a good practical value.
- 2) Choose the hysteresis voltage (V_{HB}), the voltage between the upper and lower thresholds. In this example, choose $V_{HB} = 50mV$ (see Figure 3).

Low IBIAS, +1.4V/800nA, Rail-to-Rail Op Amps with +1.2V Buffered Reference

- 3) Calculate R1:

$$\begin{aligned} R1 &= R3 \times \frac{V_{HB}}{V_{DD}} \\ &= 10M\Omega \times \frac{0.5V}{2.4V} \\ &= 210k\Omega \end{aligned}$$

- 4) Choose the threshold voltage for V_{IN} rising (V_{THR}). In this example, choose $V_{THR} = 2.0V$.
- 5) Calculate R2:

$$\begin{aligned} R2 &= \frac{1}{\left[\left(\frac{V_{THR}}{V_{REF} \times R1} \right) - \frac{1}{R1} - \frac{1}{R3} \right]} \\ &= \frac{1}{\left[\left(\frac{2.0V}{1.2V \times 210k\Omega} \right) - \frac{1}{210k\Omega} - \frac{1}{10M\Omega} \right]} \\ &= 325k\Omega \end{aligned}$$

- 6) Verify the threshold voltages with these formulas:
 V_{IN} rising:

$$V_{THR} = V_{REF} \times R1 \times \left(\frac{1}{R1} + \frac{1}{R2} + \frac{1}{R3} \right)$$

V_{IN} falling:

$$V_{THF} = V_{THR} - \left(\frac{R1 \times V_{DD}}{R3} \right)$$

In this application, the MAX4036–MAX4039 supply current will vary, depending on the output state of the comparator.

Power Supplies and Layout

The MAX4036–MAX4039 operate from a single 1.4V (MAX4036/MAX4038) or 1.8V (MAX4037/MAX4039) to 3.6V power supply. Bypass V_{DD} with a $0.1\mu F$ capacitor to ground to minimize noise.

Good layout techniques optimize performance by decreasing the amount of stray capacitance to the op amp's inputs and outputs. To decrease stray capacitance, minimize trace lengths by placing external components close to the device.

The exposed paddle (EP) on the TDFN packages of the MAX4038 and MAX4039 is internally connected to the device substrate, V_{SS} . Connect the exposed paddle to V_{SS} or leave EP unconnected. Running traces below the exposed paddle is not recommended.

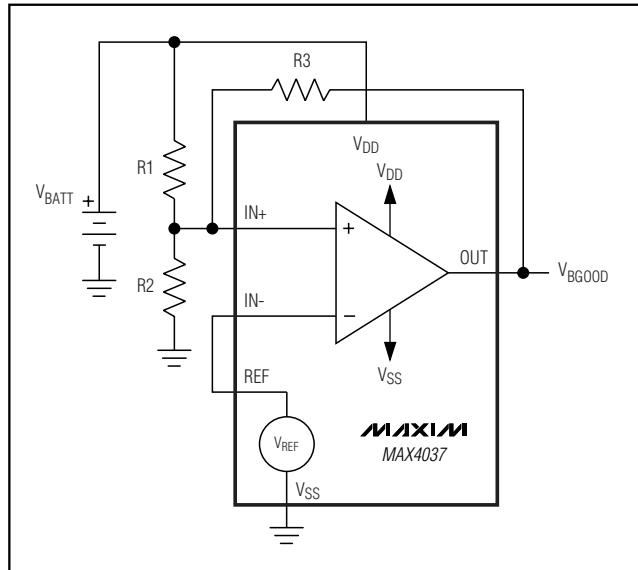


Figure 4. Battery Monitoring

Selector Guide

PART	NO. OF AMPLIFIERS	REFERENCE
MAX4036	1	—
MAX4037	1	✓
MAX4038	2	—
MAX4039	2	✓

Chip Information

MAX4036 TRANSISTOR COUNT: 49

MAX4037 TRANSISTOR COUNT: 119

MAX4038 TRANSISTOR COUNT: 146

MAX4039 TRANSISTOR COUNT: 146

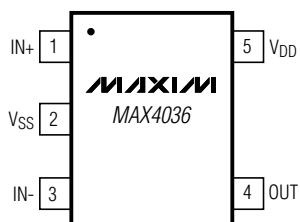
PROCESS: BiCMOS

Low IBIAS, +1.4V/800nA, Rail-to-Rail Op Amps with +1.2V Buffered Reference

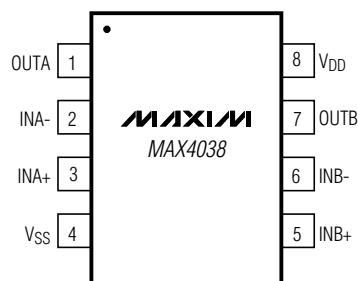
Pin Configurations

MAX4036–MAX4039

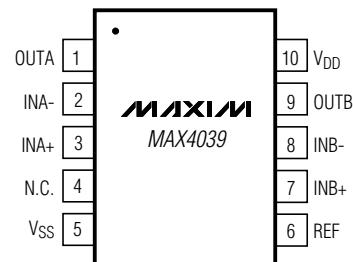
TOP VIEW



SC70



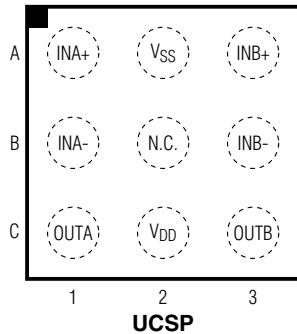
μMAX



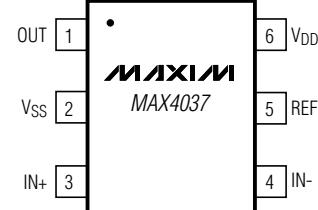
μMAX

(BUMP SIDE DOWN)

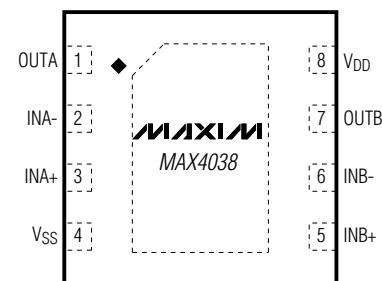
MAXIM
MAX4038



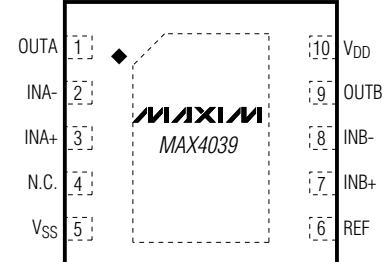
UCSP



SOT23



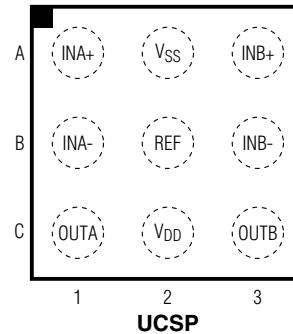
3mm x 3mm x 0.8mm TDFN
TDFN EXPOSED PAD CONNECTED TO V_{SS}



3mm x 3mm x 0.8mm TDFN
TDFN EXPOSED PAD CONNECTED TO V_{SS}

MAXIM

MAX4039

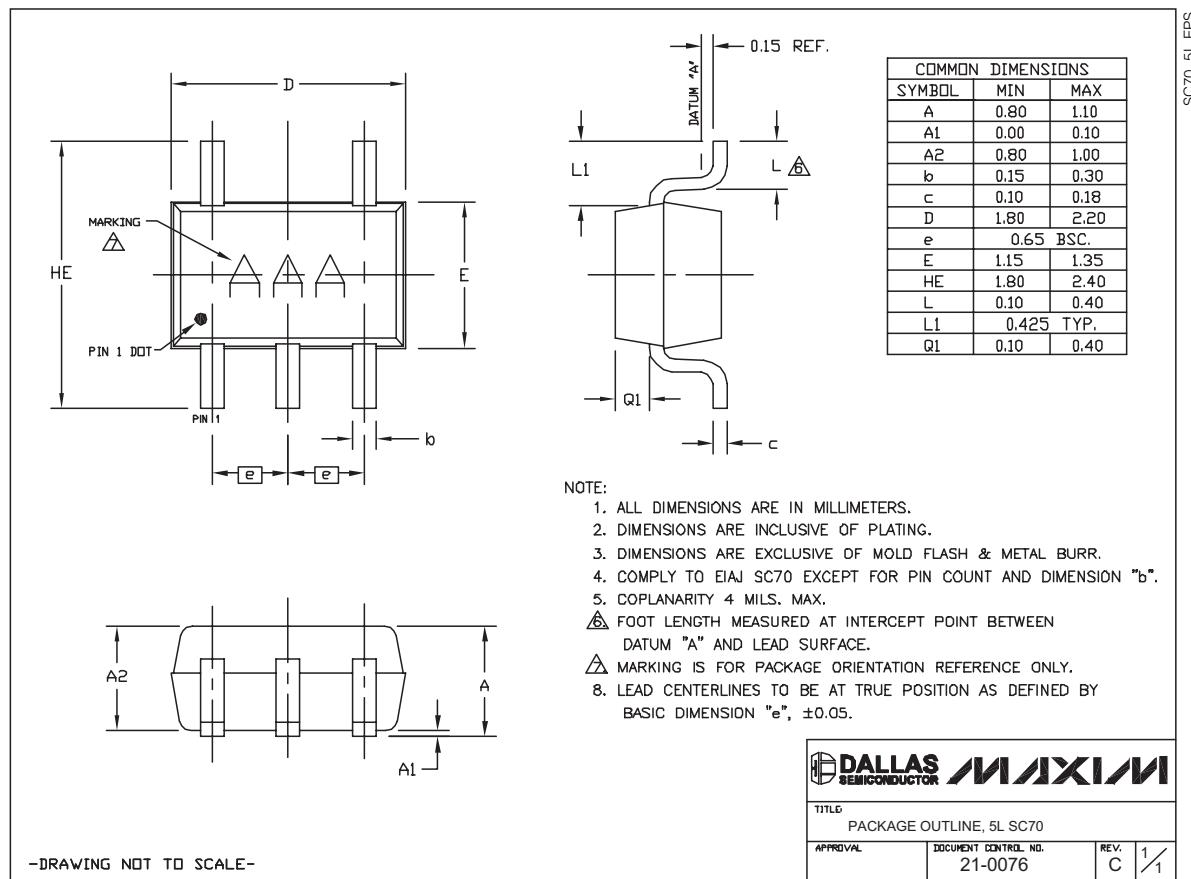


UCSP

Low IBIAS, +1.4V/800nA, Rail-to-Rail Op Amps with +1.2V Buffered Reference

Packaging Information

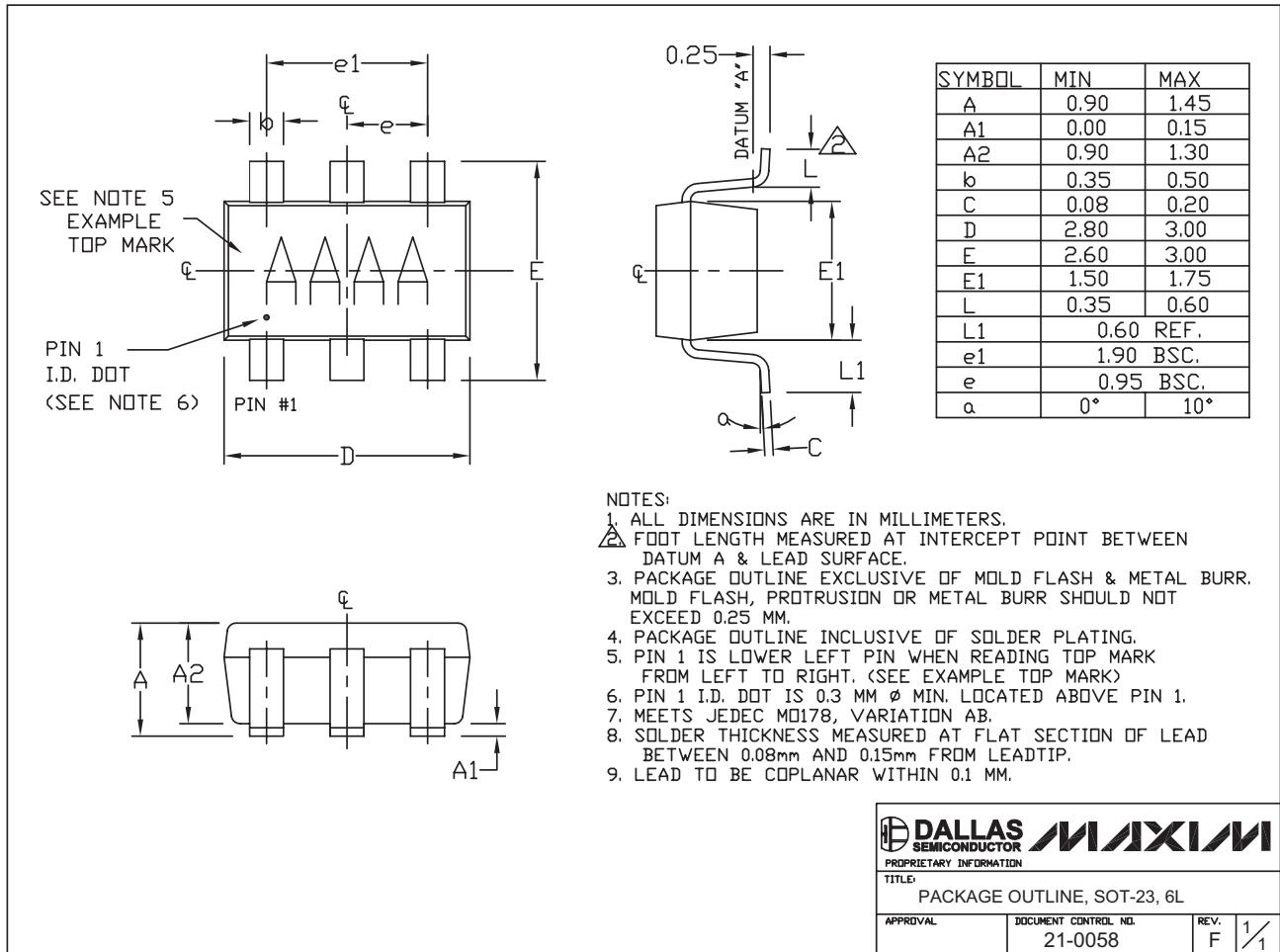
(The package drawing(s) in this data sheet may not reflect the most current specifications. For the latest package outline information, go to www.maxim-ic.com/packages.)



Low IBIAS, +1.4V/800nA, Rail-to-Rail Op Amps with +1.2V Buffered Reference

Package Information (continued)

(The package drawing(s) in this data sheet may not reflect the most current specifications. For the latest package outline information, go to www.maxim-ic.com/packages.)

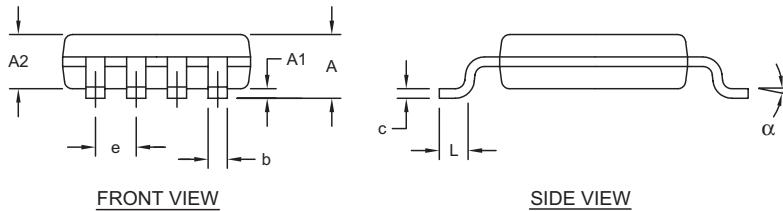
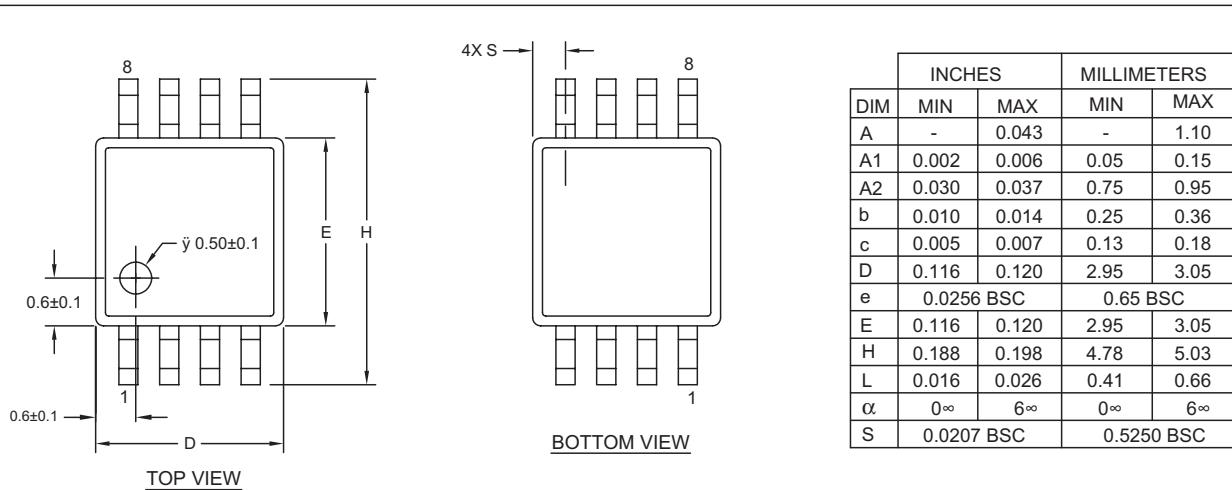


Low IBIAS, +1.4V/800nA, Rail-to-Rail Op Amps with +1.2V Buffered Reference

Package Information (continued)

(The package drawing(s) in this data sheet may not reflect the most current specifications. For the latest package outline information, go to www.maxim-ic.com/packages.)

8LUMAXD EPS



NOTES:

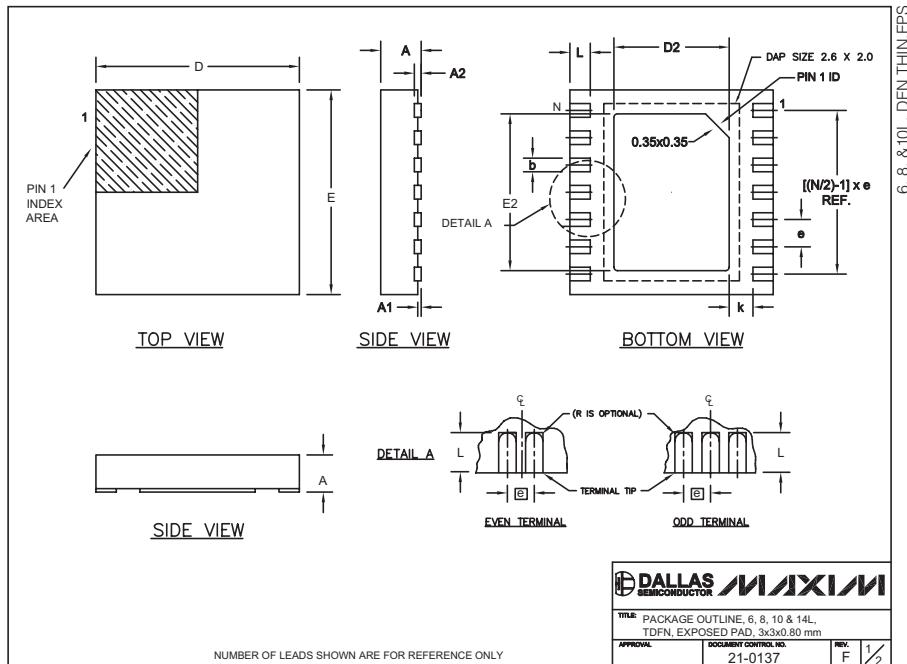
1. D&E DO NOT INCLUDE MOLD FLASH.
2. MOLD FLASH OR PROTRUSIONS NOT TO EXCEED 0.15MM (.006").
3. CONTROLLING DIMENSION: MILLIMETERS.
4. MEETS JEDEC MO-187C-AA.

DALLAS SEMICONDUCTOR	
PROPRIETARY INFORMATION	
TITLE:	
PACKAGE OUTLINE, 8L uMAX/uSOP	
APPROVAL	DOCUMENT CONTROL NO. 21-0036
	REV. J
	1/1

Low IBIAS, +1.4V/800nA, Rail-to-Rail Op Amps with +1.2V Buffered Reference

Package Information (continued)

(The package drawing(s) in this data sheet may not reflect the most current specifications. For the latest package outline information, go to www.maxim-ic.com/packages.)



COMMON DIMENSIONS		
SYMBOL	MIN.	MAX.
A	0.70	0.80
D	2.90	3.10
E	2.90	3.10
A1	0.00	0.05
L	0.20	0.40
k	0.25 MIN.	
A2	0.20 REF.	

PACKAGE VARIATIONS							
PKG. CODE	N	D2	E2	e	JEDEC SPEC	b	[$(N/2)-1$] x e
T633-1	6	1.50±0.10	2.30±0.10	0.95 BSC	MO229 / WEEA	0.40±0.05	1.90 REF
T833-1	8	1.50±0.10	2.30±0.10	0.65 BSC	MO229 / WEEC	0.30±0.05	1.95 REF
T1033-1	10	1.50±0.10	2.30±0.10	0.50 BSC	MO229 / WEED-3	0.25±0.05	2.00 REF
T1433-1	14	1.70±0.10	2.30±0.10	0.40 BSC	-----	0.20±0.03	2.40 REF
T1433-2	14	1.70±0.10	2.30±0.10	0.40 BSC	-----	0.20±0.03	2.40 REF

NOTES:

1. ALL DIMENSIONS ARE IN mm. ANGLES IN DEGREES.
2. COPLANARITY SHALL NOT EXCEED 0.08 mm.
3. WARPAGE SHALL NOT EXCEED 0.10 mm.
4. PACKAGE LENGTH/PACKAGE WIDTH ARE CONSIDERED AS SPECIAL CHARACTERISTIC(S).
5. DRAWING CONFORMS TO JEDEC MO229, EXCEPT DIMENSIONS "D2" AND "E2", AND T1433-1 & T1433-2.
6. "N" IS THE TOTAL NUMBER OF LEADS.

DALLAS SEMICONDUCTOR MAXIM

TITLE: PACKAGE OUTLINE 6, 8, 10 & 14L,
TDFN, EXPOSED PAD, 3x3x0.80 mm

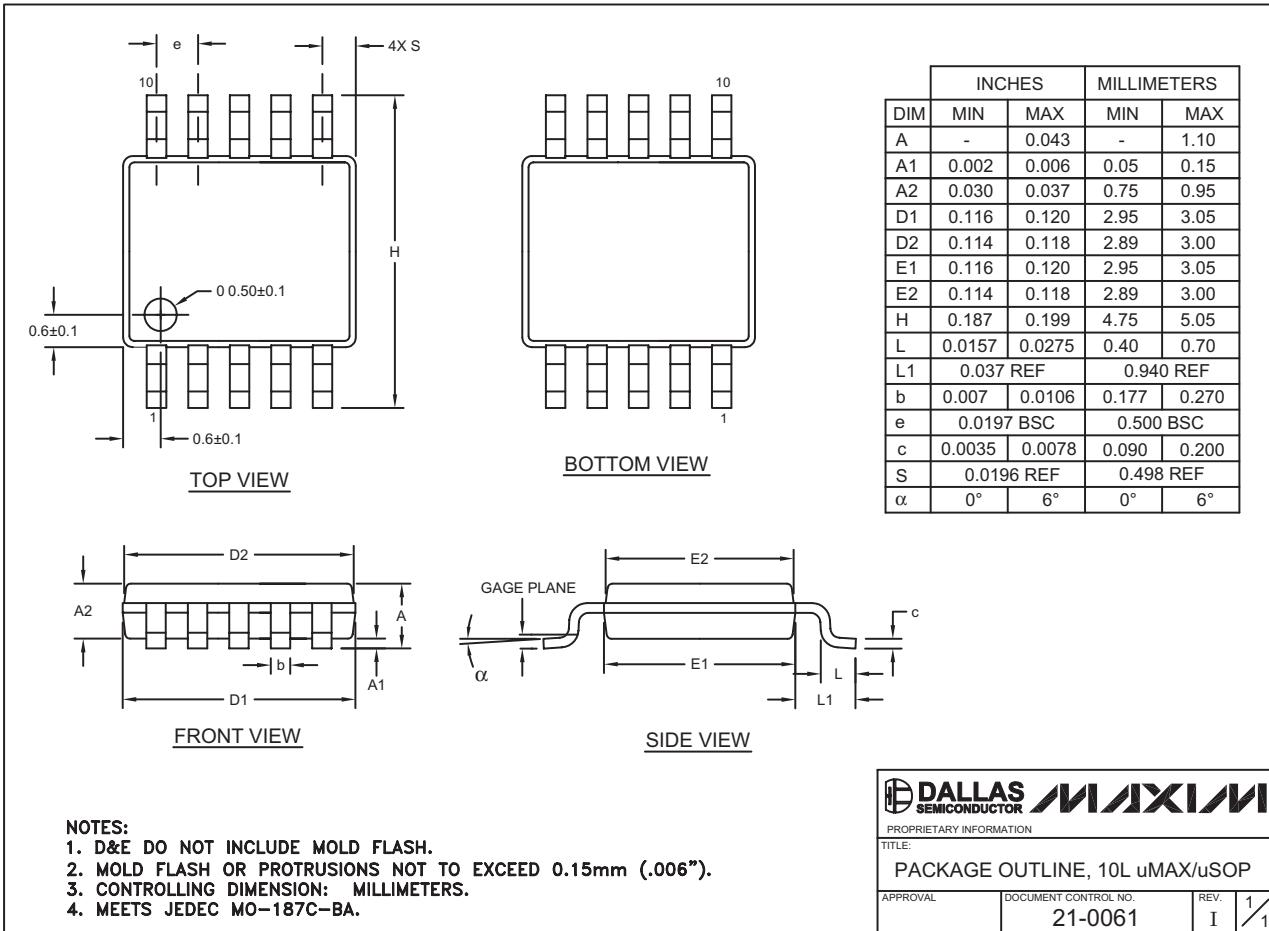
APPROVAL	DOCUMENT CONTROL NO.	REV.
	21-0137	F 2/2

Low IBIAS, +1.4V/800nA, Rail-to-Rail Op Amps with +1.2V Buffered Reference

Package Information (continued)

(The package drawing(s) in this data sheet may not reflect the most current specifications. For the latest package outline information, go to www.maxim-ic.com/packages.)

10L uMAX/EPS



DALLAS SEMICONDUCTOR		MAXIM
PROPRIETARY INFORMATION		
TITLE: PACKAGE OUTLINE, 10L uMAX/uSOP		
APPROVAL	DOCUMENT CONTROL NO. 21-0061	REV. I 1/1

Low IBIAS, +1.4V/800nA, Rail-to-Rail Op Amps with +1.2V Buffered Reference

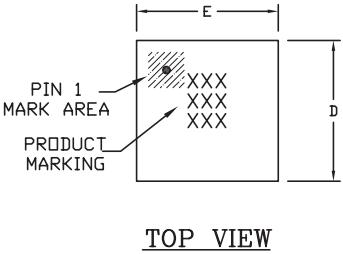
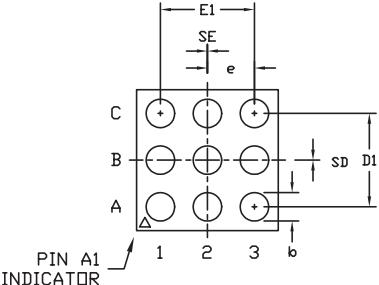
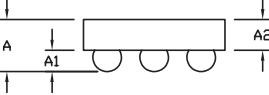
Package Information (continued)

(The package drawing(s) in this data sheet may not reflect the most current specifications. For the latest package outline information, go to www.maxim-ic.com/packages.)

TOP VIEW		COMMON DIMENSIONS		PKG. CODE	VARIABLE DIMENSIONS		DEPOPULATED SOLDER BALLS
		A	0.62+0.05-0.08		D	E	
PIN 1 MARK AREA	XXX XXX XXX	A1	0.29±0.02		B9-1	1.52±0.05	1.52±0.05
PRODUCT MARKING		A2	0.33 REF.		B9-2	1.52±0.05	1.52±0.05
		b	Ø0.35±0.03		B9-3	1.52±0.05	B1, B2, B3
		D1	1.00 BASIC		B9-4	1.60±0.05	1.60±0.05
		E1	1.00 BASIC		B9-5	1.60±0.05	B2
		e	0.50 BASIC		B9-6	1.60±0.05	B1, B2, B3
		SD	0.00 BASIC				
		SE	0.00 BASIC				

NOTES:

1. ALL DIMENSIONS ARE IN MILLIMETERS.
2. PRODUCT MARKING: NUMBER OF CHARACTERS AND LINES VARY PER PRODUCT.

DALLAS SEMICONDUCTOR MAXIM
PROPRIETARY INFORMATION
TITLE: PACKAGE OUTLINE, 3x3 UCSP
APPROVAL DOCUMENT CONTROL NO. REV. 21-0093 1 1/1

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